

# Vishay Semiconductors

## Silicon PIN Photodiode



# FEATURESPackage type

Package type: leadedPackage form: T-1

• Dimensions (in mm): Ø 3

High radiant sensitivity

 Daylight blocking filter matched with 850 nm to 950 nm emitters

Fast response times

• Angle of half sensitivity:  $\varphi = \pm 20^{\circ}$ 

 Package matched with IR emitter series VSLB3940, TSUS4300, and TSAL4400

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

# Pb-free



RoHS

FREE GREEN

### **DESCRIPTION**

TEFD4300F is a silicon PIN photodiode with high radiant sensitivity in black, T-1 plastic package with daylight blocking filter. Filter bandwitdth is matched with 850 nm to 950 nm IR emitters.

#### **APPLICATIONS**

- High speed photo detector for data transmission
- · Optical switches
- · Counters and sorters
- Interrupters
- Encoders
- · Position sensors

| PRODUCT SUMMARY |                      |         |                       |  |
|-----------------|----------------------|---------|-----------------------|--|
| COMPONENT       | I <sub>ra</sub> (μΑ) | φ (deg) | λ <sub>0.5</sub> (nm) |  |
| TEFD4300F       | 17                   | ± 20    | 770 to 1070           |  |

#### Note

• Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |               |                                |              |  |  |
|----------------------|---------------|--------------------------------|--------------|--|--|
| ORDERING CODE        | PACKAGING     | REMARKS                        | PACKAGE FORM |  |  |
| TEFD4300F            | Bulk          | MOQ: 5000 pcs, 5000 pcs/bulk   | T-1          |  |  |
| TEFD4300F-QS21       | Tape and reel | MOQ: 10 000 pcs, 2000 pcs/reel | T-1          |  |  |

#### Note

· MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |             |      |  |
|--|--|-------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION                               | SYMBOL            | VALUE       | UNIT |  |
| Reverse voltage  |  | $V_{R}$           | 60          | V    |  |
| Power dissipation  | T <sub>amb</sub> ≤ 25 °C                     | P <sub>V</sub>    | 215         | mW   |  |
| Junction temperature   |  | Tj                | 100         | °C   |  |
| Operating temperature range  |  | T <sub>amb</sub>  | -40 to +100 | °C   |  |
| Storage temperature range  |  | T <sub>stg</sub>  | -40 to +100 | °C   |  |
| Soldering temperature  | $t \le 3 \text{ s}, 2 \text{ mm from case}$  | T <sub>sd</sub>   | 260         | °C   |  |
| Thermal resistance junction / ambient  | Connected with Cu wire, 0.14 mm <sup>2</sup> | R <sub>thJA</sub> | 450         | K/W  |  |



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| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |      |      |      |      |
|---|---|-------------------|------|------|------|------|
| PARAMETER   | TEST CONDITION  | SYMBOL            | MIN. | TYP. | MAX. | UNIT |
| Forward voltage   | I <sub>F</sub> = 50 mA  | V <sub>F</sub>    | -    | 1    | -    | V    |
| Breakdown voltage   | I <sub>R</sub> = 100 μA, E = 0  | V <sub>(BR)</sub> | 60   | -    | -    | V    |
| Reverse dark current  | V <sub>R</sub> = 10 V, E = 0  | I <sub>ro</sub>   | -    | 0.15 | 3    | nA   |
| Diode capacitance   | $V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$                         | C <sub>D</sub>    | -    | 3.3  | -    | pF   |
|   | V <sub>R</sub> = 5 V, f = 1 MHz, E = 0                                  | C <sub>D</sub>    | -    | 1.2  | -    | pF   |
| Open circuit voltage  | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$                     | V <sub>OC</sub>   | -    | 350  | -    | mV   |
| Temperature coefficient of V <sub>O</sub>   | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$                     | TK <sub>Vo</sub>  | -    | -2.6 | -    | mV/K |
| Short circuit current   | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$                     | I <sub>k</sub>    | -    | 15   | -    | μΑ   |
| Temperature coefficient of I <sub>k</sub>   | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$                     | TK <sub>lk</sub>  | -    | 0.1  | -    | %/K  |
| Reverse light current   | $E_e$ = 1 mW/cm <sup>2</sup> , $\lambda$ = 950 nm, $V_R$ = 5 V          | I <sub>ra</sub>   | 9    | 17   | 27   | μA   |
| Angle of half sensitivity   |   | φ                 | -    | ± 20 | -    | deg  |
| Wavelength of peak sensitivity  |   | $\lambda_{p}$     | -    | 950  | -    | nm   |
| Range of spectral bandwidth   |   | λ <sub>0.5</sub>  | 770  | -    | 1070 | nm   |
| Rise time   | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$ | t <sub>r</sub>    | -    | 100  | -    | ns   |
| Fall time   | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$ | t <sub>f</sub>    | -    | 100  | -    | ns   |

## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

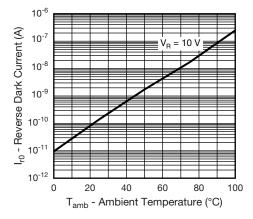


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

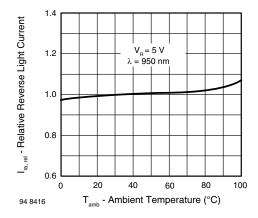


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



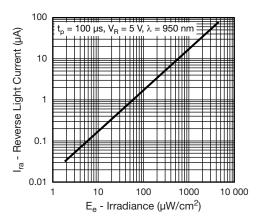


Fig. 3 - Reverse Light Current vs. Irradiance

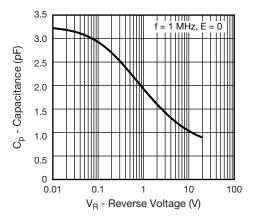


Fig. 4 - Diode Capacitance vs. Reverse Voltage

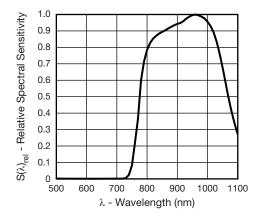


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

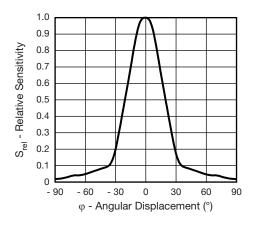


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

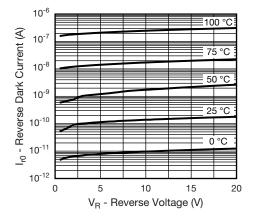
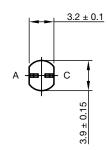
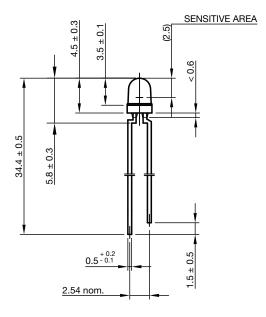


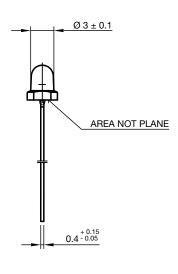
Fig. 7 - Dark Current vs. Reverse Voltage

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#### **PACKAGE DIMENSIONS** in millimeters









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